MBR1040FCT THRU MBR10200FCT

List

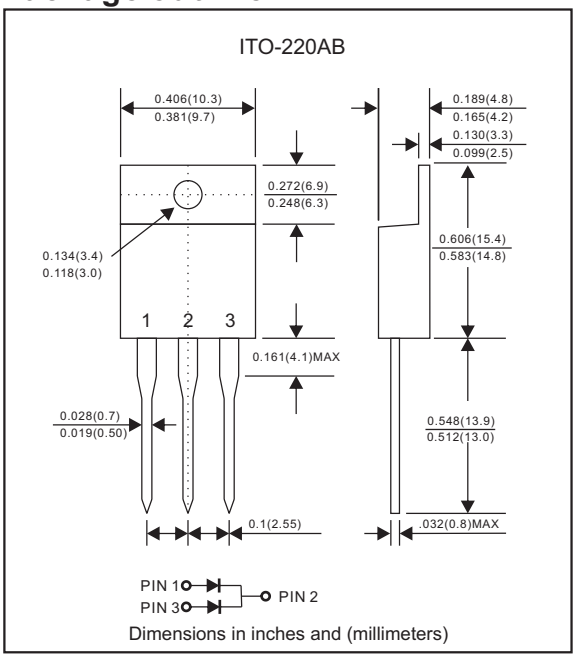
MBR1040FCT THRU MBR10200FCT

10A High Barrier Power Schottky Rectifiers - 40V-200V

Features

- 150°C operating junction temperature.
- Low power loss, high efficiency.
- High current capability
- High surge capability.
- Guardring for overvoltage protection.
- Low stored charge majority carrier conduction
- Silicon epitaxial planar chip, metal silicon junction.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228
- Suffix "-H" indicates Halogen-free parts, ex. MBR1040FCT-H.

Package outline



Mechanical data

- Epoxy : UL94-V0 rated flame retardant
- Case : JEDEC ITO-220AB molded plastic body over passivated chip
- Lead : Axial leads, solderable per MIL-STD-202, Method 208 guranteed
- Polarity: As marked
- Mounting Position : Any
- Weight : Approximated 1.70 gram

Maximum ratings and Electrical Characteristics (AT T_A=25°C unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current	See Fig.1	I_O			10.0	A
Forward surge current	8.3ms single half sine-wave (JEDEC methode)	I_{FSM}			125	A
Reverse current	$V_R = V_{RRM}$ T_J = 25°C	I_R			0.1	mA
	$V_R = V_{RRM}$ T_J = 125°C				15	
Thermal resistance	Junction to case	$R_{\theta JC}$		3.0		°C/W
Storage temperature		T_{STG}	-65		+175	°C

SYMBOLS	V_{RRM} *1 (V)	V_{RMS} *2 (V)	V_R *3 (V)	V_F *4 (V)	V_F *5 (V)	Operating temperature T_J, (°C)
MBR1040FCT	40	28	40	0.70	0.84	-55 to +150
MBR1045FCT	45	31.5	45			
MBR1050FCT	50	35	50	0.80	0.95	
MBR1060FCT	60	42	60			
MBR1080FCT	80	56	80	0.85		
MBR10100FCT	100	70	100			
MBR10150FCT	150	105	150	0.95	1.00	
MBR10200FCT	200	140	200			

*1 Repetitive peak reverse voltage

*2 RMS voltage

*3 Continuous reverse voltage

*4 Maximum forward voltage IF = 5.0A, 25°C

*5 Maximum of forward voltage IF=10.0A, 25°C

Rating and characteristic curves (MBR1040FCT THRU MBR10200FCT)

FIG. 1 – FORWARD CURRENT DERATING CURVE

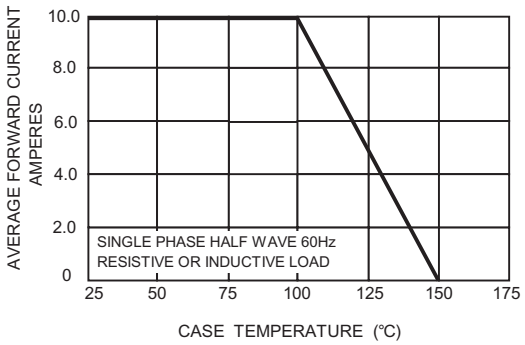


FIG. 2 – MAXIMUM NON-REPETITIVE SURGE CURRENT

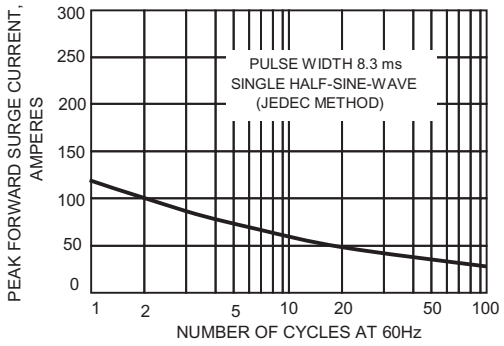


FIG.3-TYPICAL REVER CHARACTERISTICS

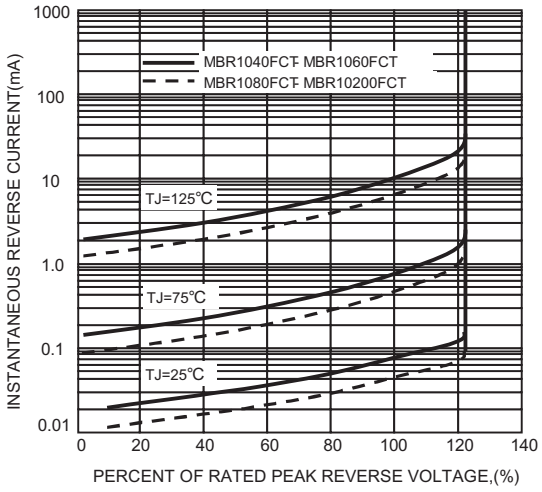


FIG.4-TYPICAL FORWARD CHARACTERISTICS

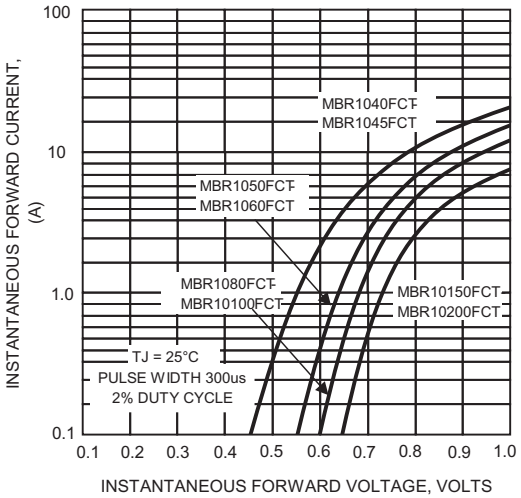
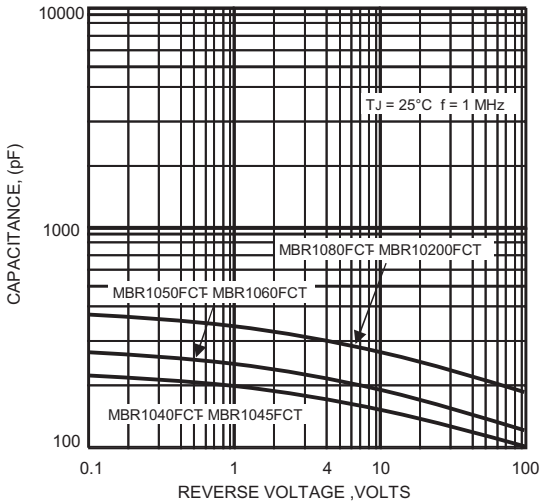


FIG.5 – TYPICAL JUNCTION CAPACITANCE



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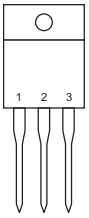
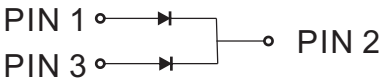
Pinning information

Pin	Simplified outline	Symbol
Pin1 anode Pin2 cathode Pin3 anode		

Marking

Type number	Marking code
MBR1040FCT	MBR1040FCT
MBR1045FCT	MBR1045FCT
MBR1050FCT	MBR1050FCT
MBR1060FCT	MBR1060FCT
MBR1080FCT	MBR1080FCT
MBR10100FCT	MBR10100FCT
MBR10150FCT	MBR10150FCT
MBR10200FCT	MBR10200FCT

Tube packing

PACKAGE	TUBE (pcs)	TUBE SIZE (m/m)	BOX (pcs)	INNER BOX (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
ITO-220AB	50	535*32*7.0	2000	550*167*75	570*345*170	8,000	23.0

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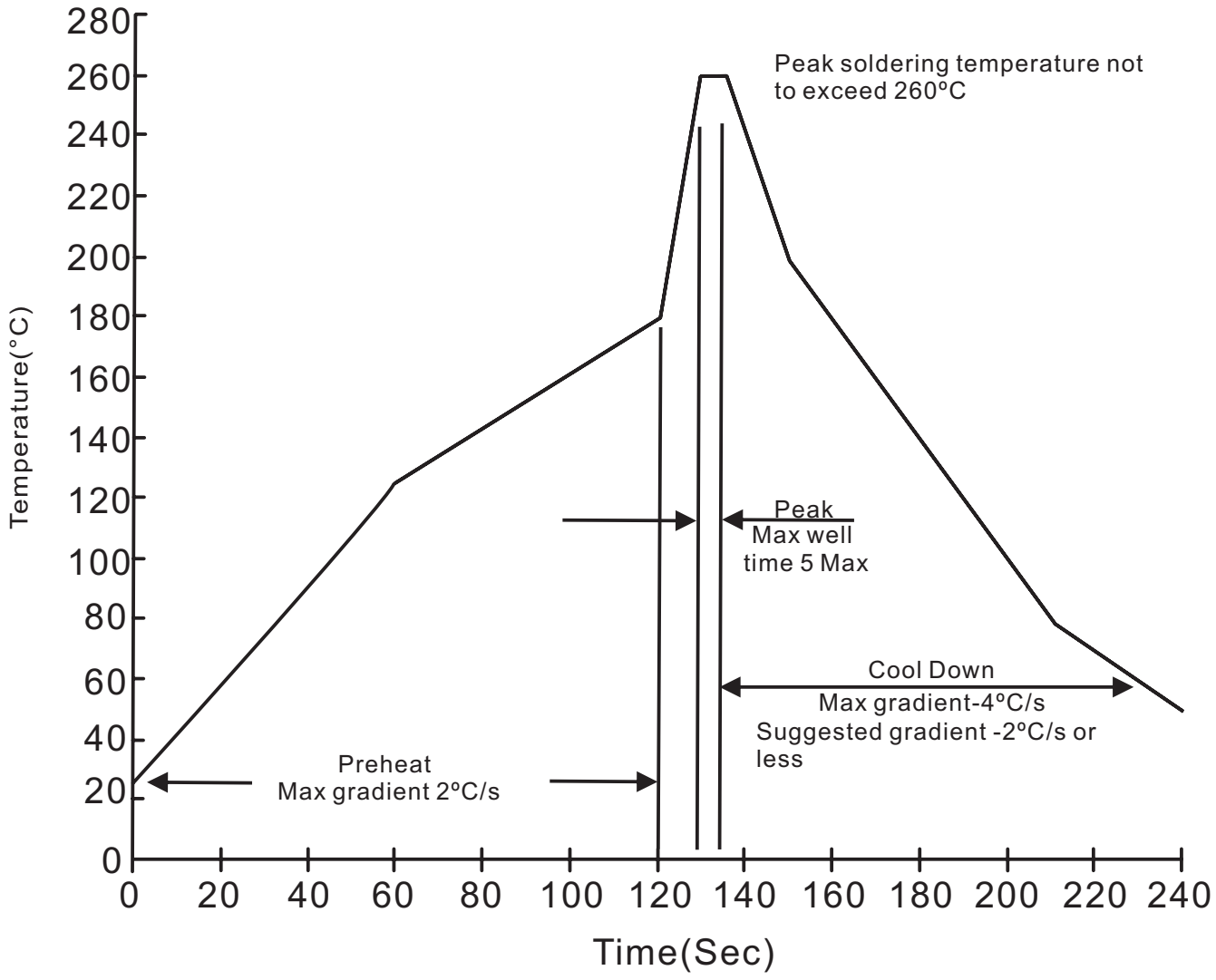
Suggested thermal profiles for soldering processes

1.Lead free temperature profile wave-soldering



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High reliability test capabilities

Item Test	Conditions	Reference
1. Solder Resistance	at 260±5°C for 10±2sec. immerse body into solder 1/16"±1/32"	MIL-STD-750D METHOD-2031
2. Solderability	at 245±5°C for 5 sec.	MIL-STD-202F METHOD-208
3. High Temperature Reverse Bias	V_R=80% rate at T_J=150°C for 168 hrs.	MIL-STD-750D METHOD-1038
4. Forward Operation Life	Rated average rectifier current at T_A=25°C for 500hrs.	MIL-STD-750D METHOD-1027
5. Intermittent Operation Life	T_A = 25°C, I_F = I_O On state: power on for 5 min. off state: power off for 5 min. on and off for 500 cycles.	MIL-STD-750D METHOD-1036
6. Pressure Cooker	15P_{SIG} at T_A=121°C for 4 hrs.	JESD22-A102
7. Temperature Cycling	-55°C to +125°C dwelled for 30 min. and transferred for 5min. total 10 cycles.	MIL-STD-750D METHOD-1051
8. Forward Surge	8.3ms single half sine-wave , one surge.	MIL-STD-750D METHOD-4066-2
9. Humidity	at T_A=85°C, RH=85% for 1000hrs.	MIL-STD-750D METHOD-1021
10. High Temperature Storage Life	at 175°C for 1000 hrs.	MIL-STD-750D METHOD-1031